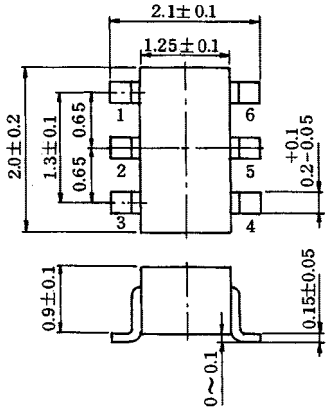
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

RN2901,RN2902,RN2903,RN2904,RN2905,RN2906

Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

- Including two devices in US6 (ultra super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1901~RN1906

Unit in mm

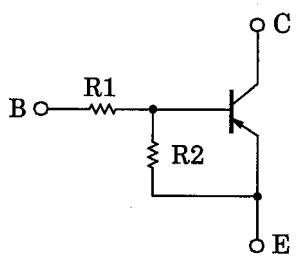


1. EMITTER 1 (E1)
2. BASE 1 (B1)
3. COLLECTOR 2 (C2)
4. EMITTER 2 (E2)
5. BASE 2 (B2)
6. COLLECTOR 1 (C1)

JEDEC	—
EIAJ	—
TOSHIBA	2-2J1A

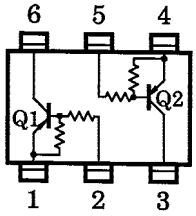
Weight: 6.8mg

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2901	4.7	4.7
RN2902	10	10
RN2903	22	22
RN2904	47	47
RN2905	2.2	47
RN2906	4.7	47

Equivalent Circuit (Top View)



Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Rating	Unit
Collector-base voltage	RN2901~2906	V_{CBO}	−50	V
Collector-emitter voltage		V_{CEO}	−50	V
Emitter-base voltage	RN2901~2904	V_{EBO}	−10	V
	RN2905, 2906		−5	
Collector current	RN2901~2906	I_C	−100	mA
Collector power dissipation		P_C *	200	mW
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	−55~150	°C

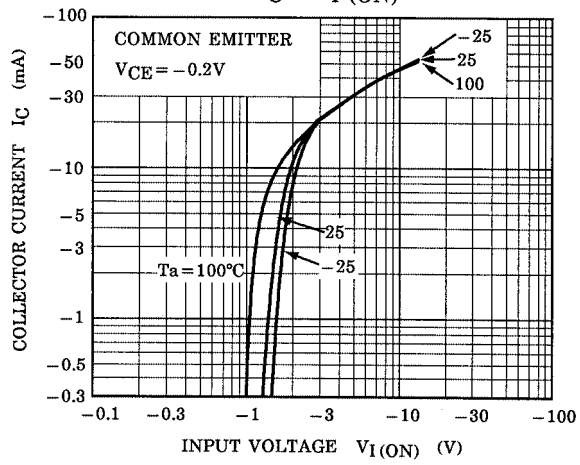
* : Total rating

Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

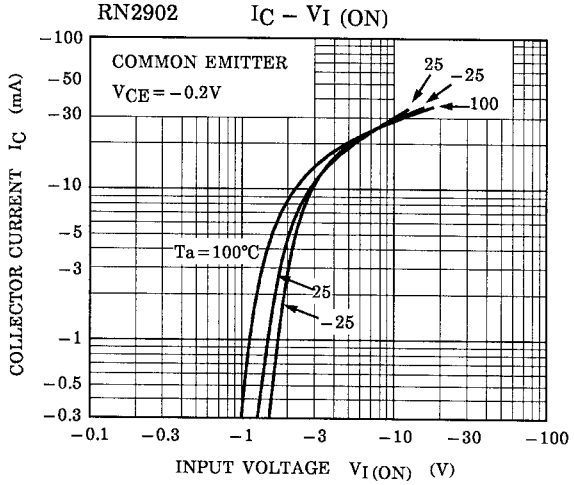
Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN2901~2906	I_{CBO}	—	V_{CB} = −50V, I_E = 0	—	—	−100	nA
		I_{CEO}	—	V_{CE} = −50V, I_B = 0	—	—	−500	
Emitter cut-off current	RN2901	I_{EBO}	—	V_{EB} = −10V, I_C = 0	−0.82	—	−1.52	mA
	RN2902		—		−0.38	—	−0.71	
	RN2903		—		−0.17	—	−0.33	
	RN2904		—		−0.082	—	−0.15	
	RN2905		—	V_{EB} = −5V, I_C = 0	−0.078	—	−0.145	
	RN2906		—		−0.074	—	−0.138	
DC current gain	RN2901	h_{FE}	—	V_{CE} = −5V I_C = −10mA	30	—	—	—
	RN2902		—		50	—	—	
	RN2903		—		70	—	—	
	RN2904		—		80	—	—	
	RN2905		—		80	—	—	
	RN2906		—		80	—	—	
Collector-emitter saturation voltage	RN2901~2906	$V_{CE\ (sat)}$	—	I_C = −5mA I_B = −0.25mA	—	−0.1	−0.3	V
Input voltage (ON)	RN2901	$V_{I\ (ON)}$	—	V_{CE} = −0.2V I_C = −5mA	−1.1	—	−2.0	V
	RN2902		—		−1.2	—	−2.4	
	RN2903		—		−1.3	—	−3.0	
	RN2904		—		−1.5	—	−5.0	
	RN2905		—		−0.6	—	−1.1	
	RN2906		—		−0.7	—	−1.3	
Input voltage (OFF)	RN2901~2904	$V_{I\ (OFF)}$	—	V_{CE} = −5V, I_C = −0.1mA	−1.0	—	−1.5	V
	RN2905, 2906		—		−0.5	—	−0.8	
Translation frequency	RN2901~2906	f_T	—	V_{CE} = −10V, I_C = −5mA	—	200	—	MHz
Collector output capacitance	RN2901~2906	C_{ob}	—	V_{CB} = −10V, I_E = 0 f = 1MHz	—	3	6	pF
Input resistor	RN2901	R1	—	—	3.29	4.7	6.11	kΩ
	RN2902		—		7	10	13	
	RN2903		—		15.4	22	28.6	
	RN2904		—		32.9	47	61.1	
	RN2905		—		1.54	2.2	2.86	
	RN2906		—		3.29	4.7	6.11	
Resistor ratio	RN2901~2904	R1/R2	—	—	0.9	1.0	1.1	—
	RN2905		—		0.0421	0.0468	0.0515	
	RN2906		—		0.09	0.1	0.11	

(Q1, Q2 Common)

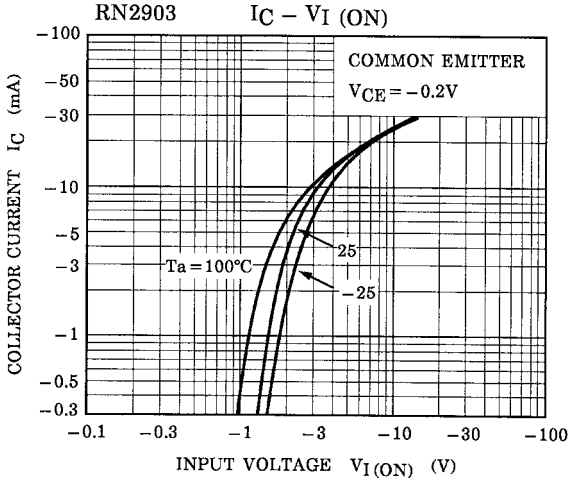
RN2901 $I_C - V_{I\,(ON)}$



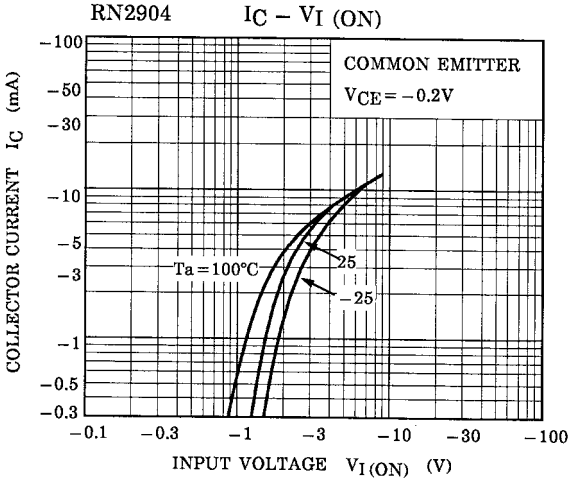
RN2902 $I_C - V_{I\,(ON)}$



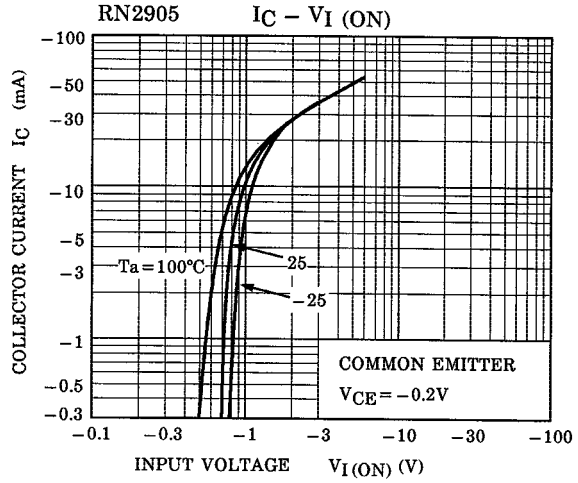
RN2903 $I_C - V_{I\,(ON)}$



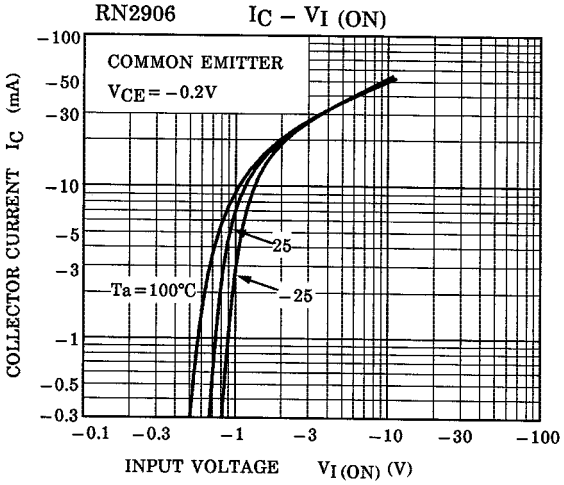
RN2904 $I_C - V_{I\,(ON)}$



RN2905 $I_C - V_{I\,(ON)}$

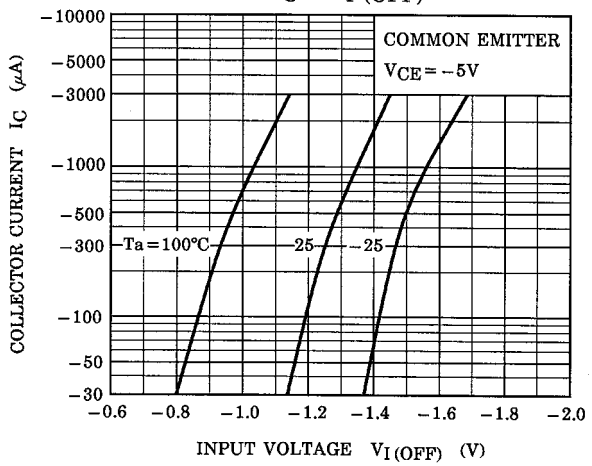


RN2906 $I_C - V_{I\,(ON)}$

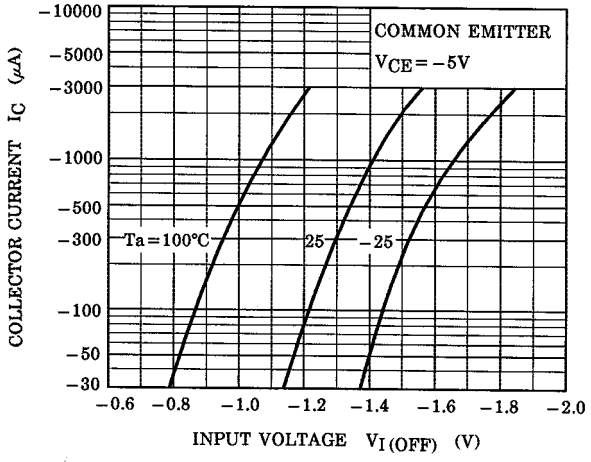


(Q1, Q2 Common)

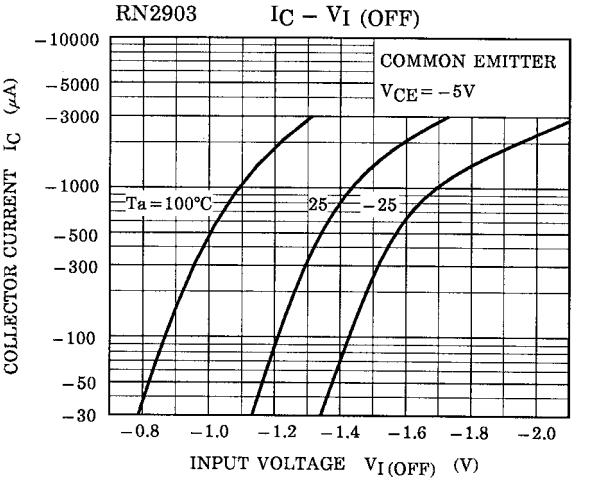
RN2901 $I_C - V_{I\,(OFF)}$



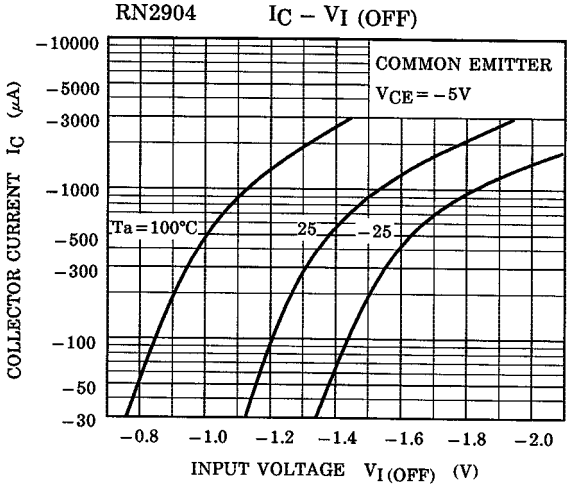
RN2902 $I_C - V_{I\,(OFF)}$



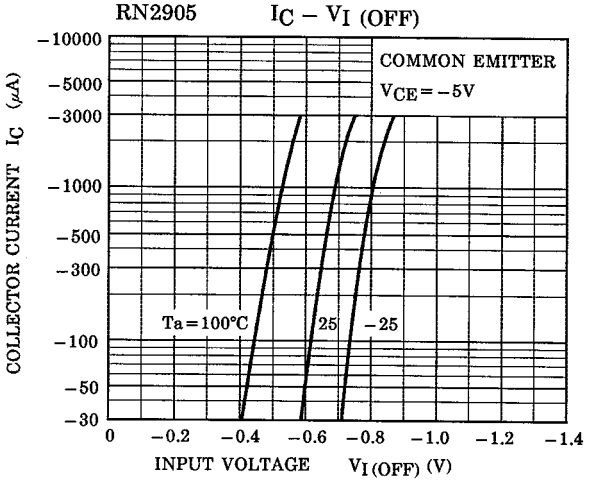
RN2903 $I_C - V_{I\,(OFF)}$



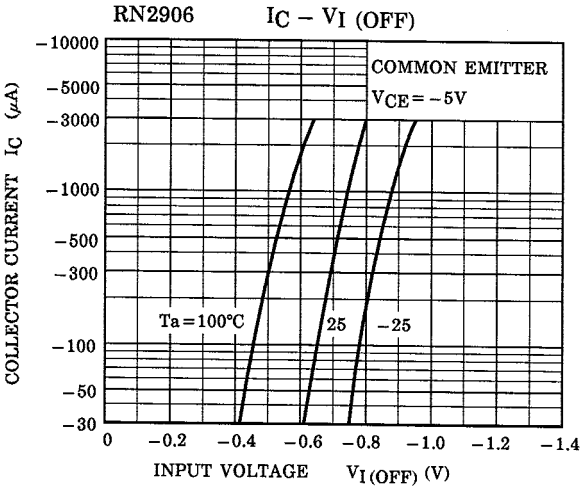
RN2904 $I_C - V_{I\,(OFF)}$



RN2905 $I_C - V_{I\,(OFF)}$

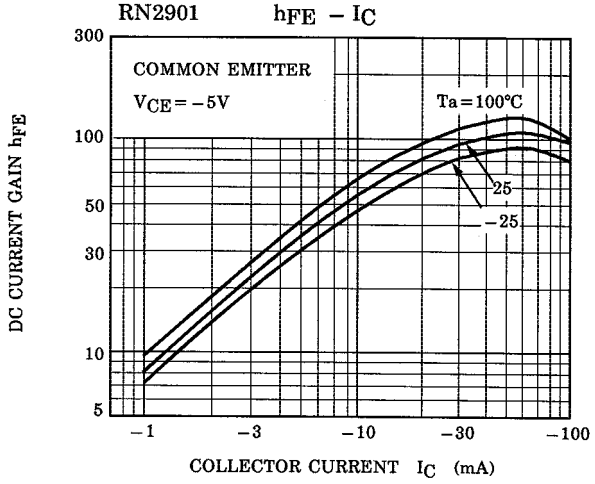


RN2906 $I_C - V_{I\,(OFF)}$

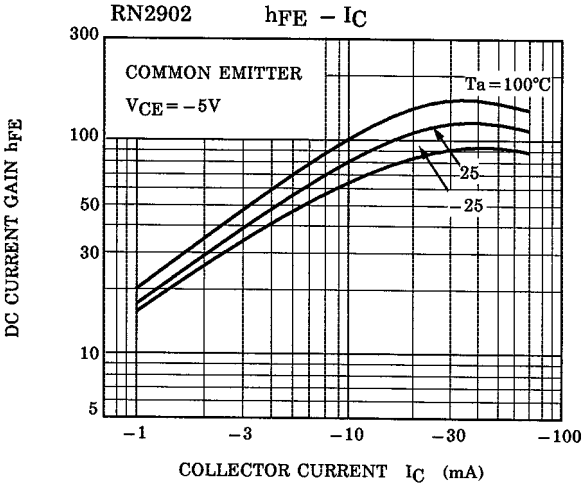


(Q1, Q2 Common)

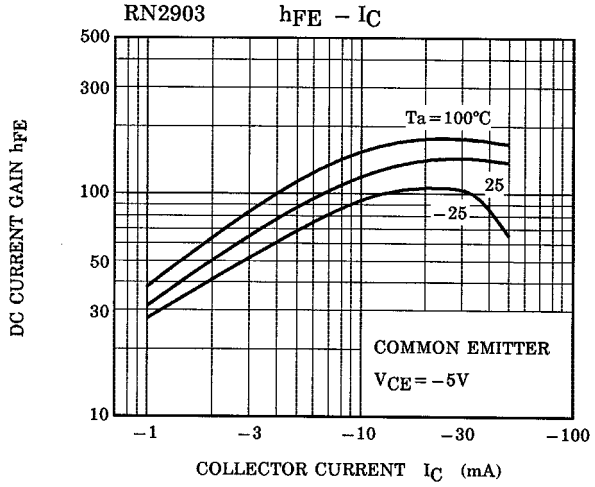
RN2901 h_{FE} – I_C



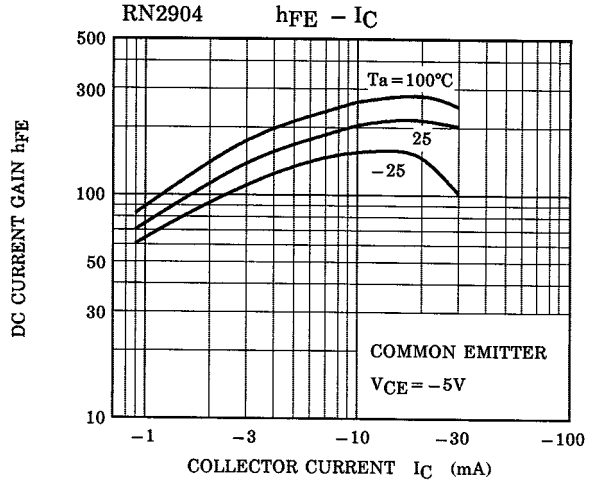
RN2902 h_{FE} – I_C



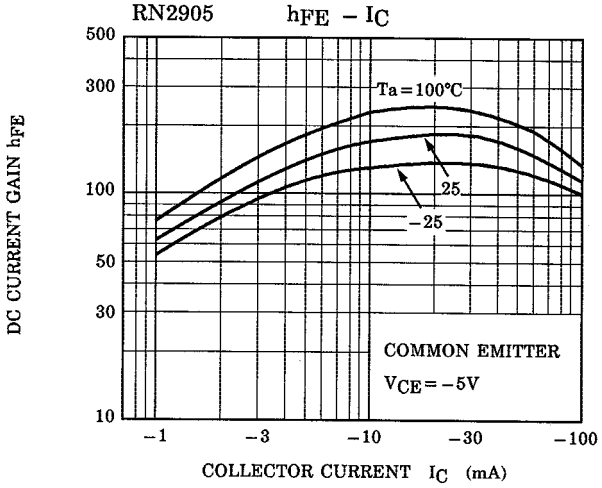
RN2903 h_{FE} – I_C



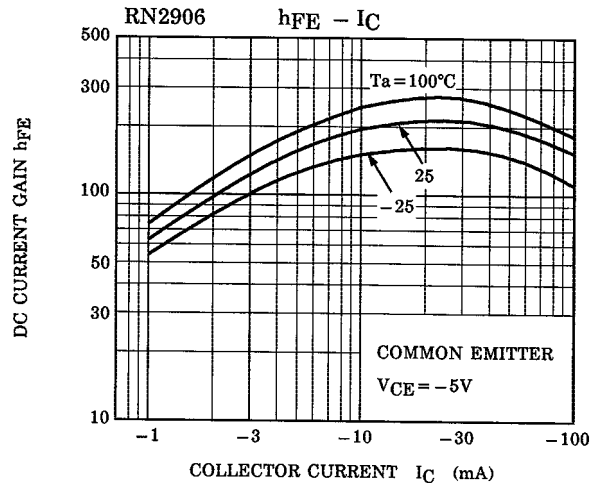
RN2904 h_{FE} – I_C

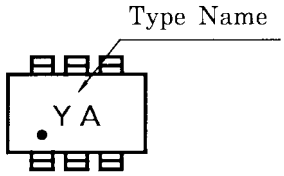
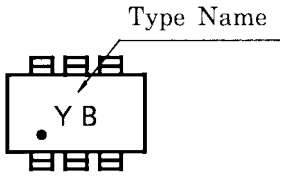
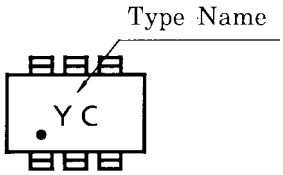
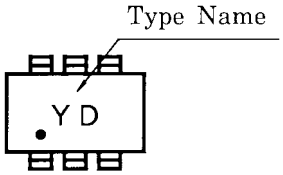
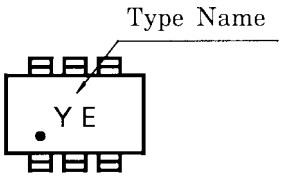
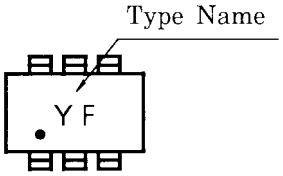


RN2905 h_{FE} – I_C



RN2906 h_{FE} – I_C



Type Name	Marking
RN2901	
RN2902	
RN2903	
RN2904	
RN2905	
RN2906	

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000707EAA

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